



20V N-Channel Enhancement Mode MOSFET

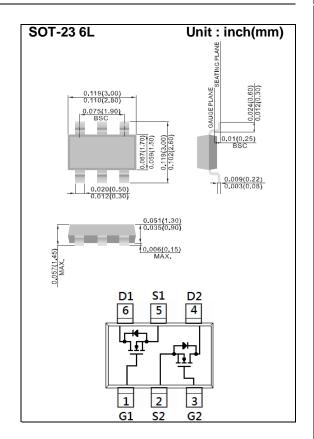
Voltage 20 V Current 5.2A

Features

- RDS(ON), VGS@4.5V, ID@5.2A<29m Ω
- RDS(ON) , VGS@2.5V, ID@3.7A<42mΩ
- RDS(ON) , VGS@1.8V, ID@1.6A<85mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S16



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V_{GS}	<u>+</u> 12	V
Continuous Drain Current		I _D	5.2	А
Pulsed Drain Current		I _{DM}	20.8	Α
Power Dissipation	T _a =25°C	P_{D}	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.5	0.77	1.2	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =5.2A	-	26	29	mΩ
		V _{GS} =2.5V, I _D =3.7A	-	35	42	
		V _{GS} =1.8V, I _D =1.6A	-	62	85	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	1	0.01	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =10V, I _D =5.2A, V _{GS} =4.5V ^(Note 1,2)	-	7	-	nC
Gate-Source Charge	Q_gs		-	1.3	-	
Gate-Drain Charge	Q_gd		-	2	-	
Input Capacitance	Ciss	V _{DS} =10V, V _{GS} =0V,	-	513	-	pF
Output Capacitance	Coss		-	74	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	60	-	
Switching						
Turn-On Delay Time	td _(on)	101/ 1 5 0 1	-	6.2	-	
Turn-On Rise Time	tr	V_{DD} =10V, I_{D} =5.2A, V_{GS} =4.5V, R_{G} =6 Ω (Note 1,2)		56		ns
Turn-Off Delay Time	td _(off)		-	23	-	
Turn-Off Fall Time	tf	K _G =012	-	13	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I _S		-	_	1.5	А
Diode Forward Current	.3			ļ		
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.71	1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

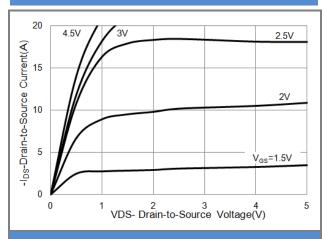


Fig.1 On-Region Characteristics

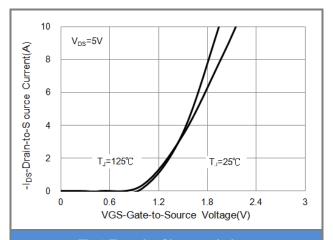


Fig.2 Transfer Characteristics

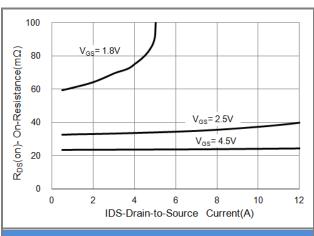


Fig.3 On-Resistance vs. Drain Current

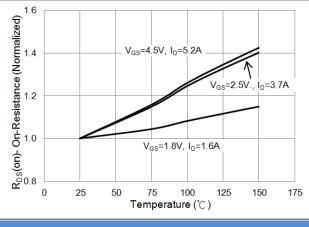


Fig.4 On-Resistance vs. Junction temperature

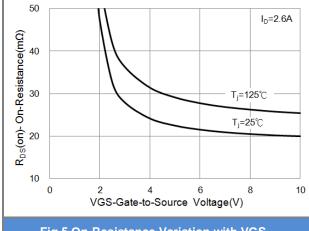


Fig.5 On-Resistance Variation with VGS.

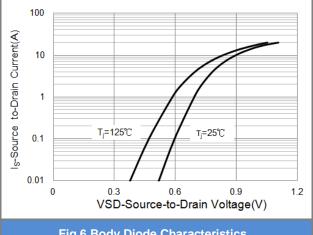


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

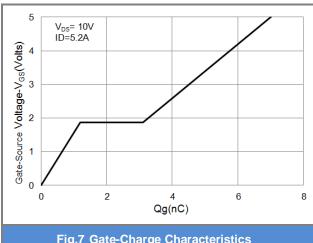


Fig.7 Gate-Charge Characteristics

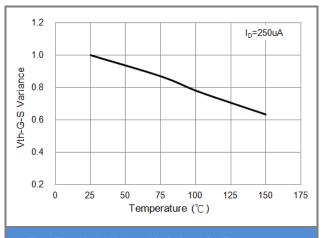


Fig.8 Threshold Voltage Variation with Temperature

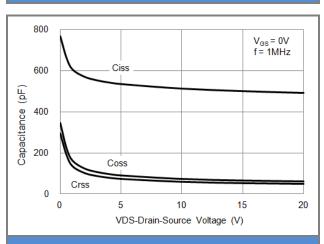


Fig.9 Capacitance vs. Drain-Source Voltage.

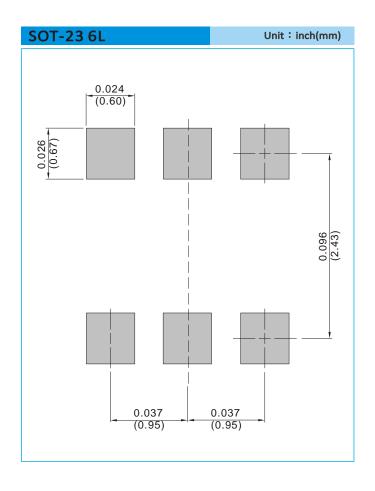




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJS6816_S1_00001	SOT-23 6L	3K pcs / 7" reel	SE6	Halogen free
PJS6816_S2_00001	SOT-23 6L	10K pcs / 13" reel	SE6	Halogen free

MOUNTING PAD LAYOUT







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